

ECE 342

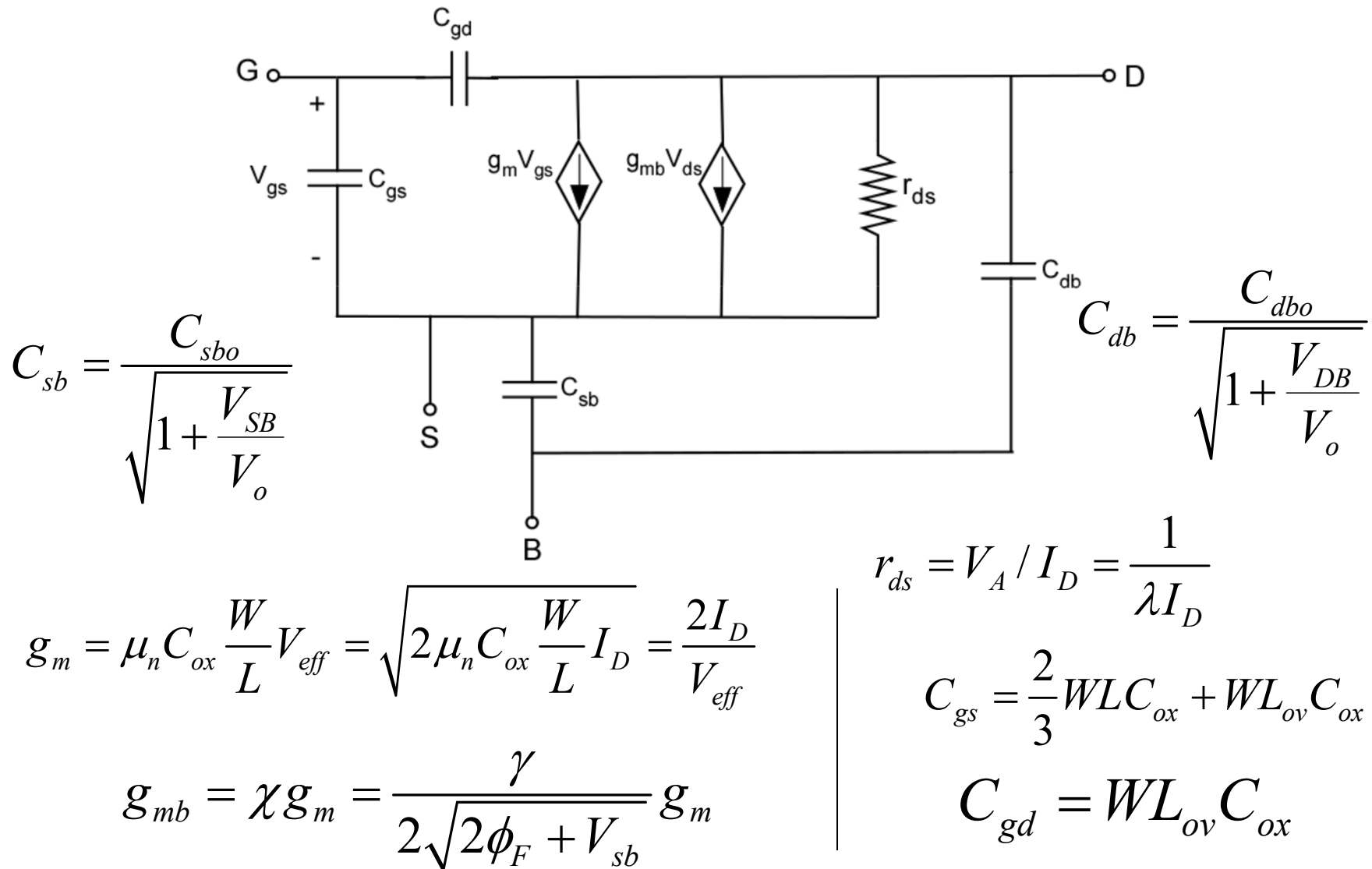
Electronic Circuits

Lecture 23

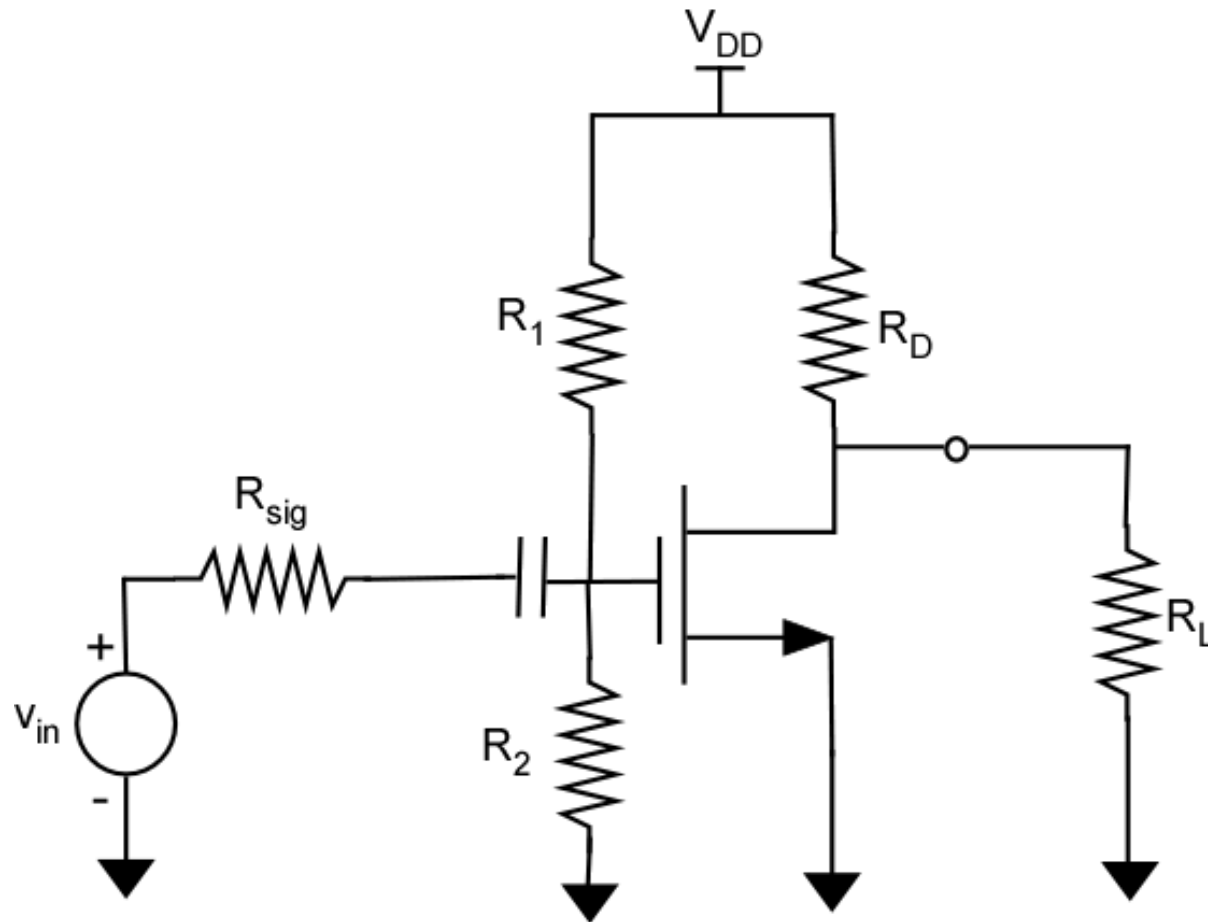
Miller Effect

Jose E. Schutt-Aine
Electrical & Computer Engineering
University of Illinois
jesa@illinois.edu

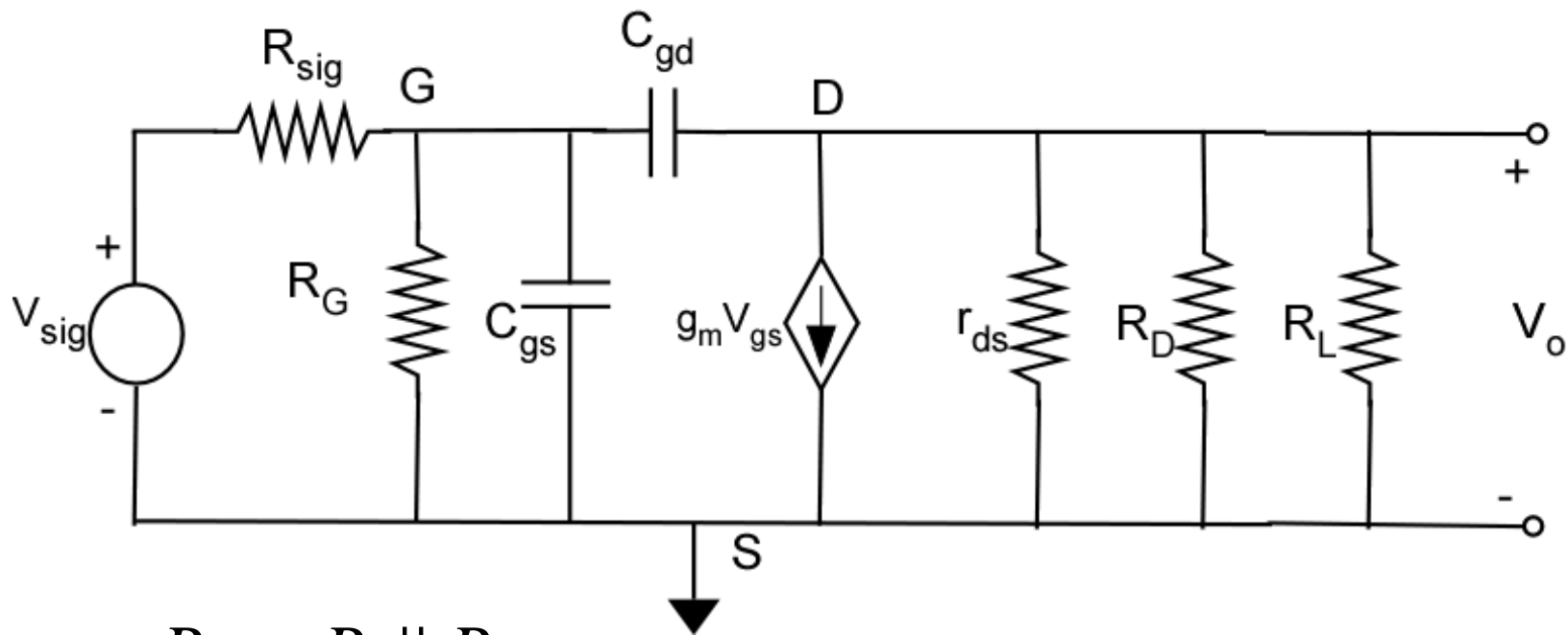
MOSFET High-Frequency Model



CS - High-Frequency Response



CS - High-Frequency Response

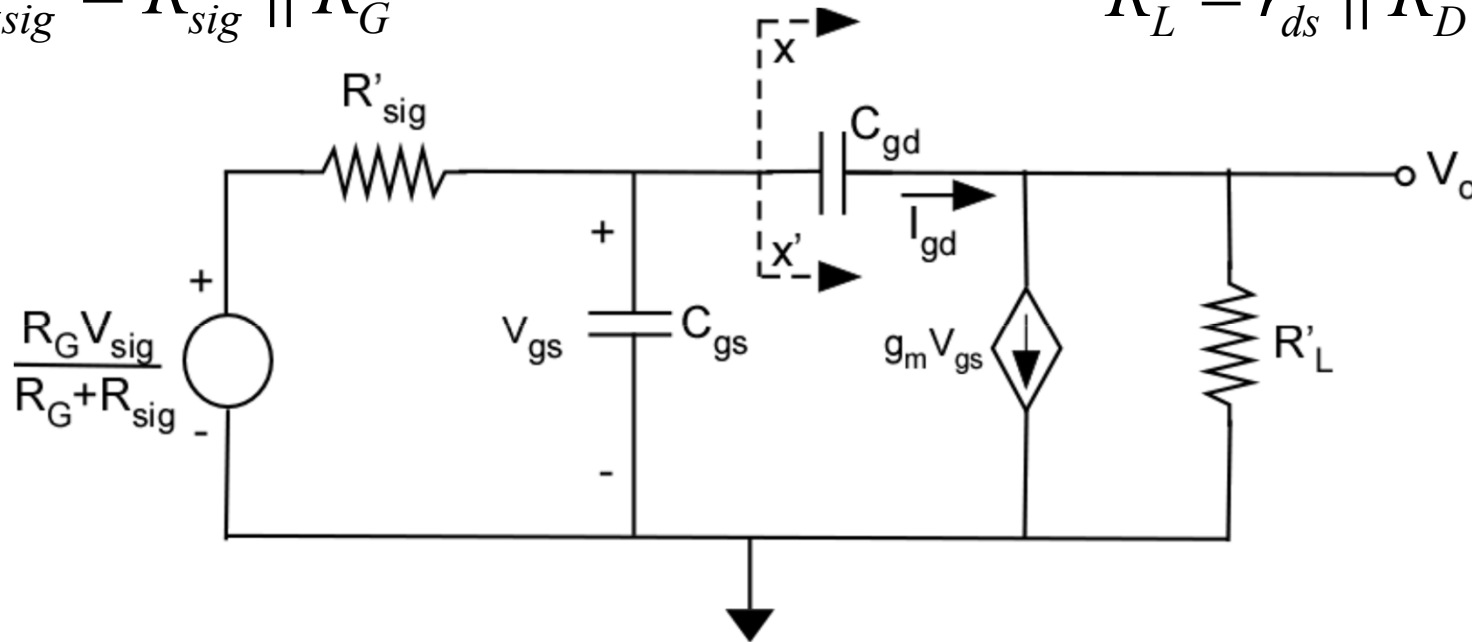


$$R_G = R_1 \parallel R_2$$

CS - High-Frequency Response

$$R'_{sig} = R_{sig} \parallel R_G$$

$$R'_L = r_{ds} \parallel R_D \parallel R_L$$



$$I_{gd} = sC_{gd} (V_{gs} - V_o) = sC_{gd} \left[V_{gs} - (-g_m R'_L V_{gs}) \right]$$

$$I_{gd} = sC_{gd} (1 + g_m R'_L) V_{gs}$$

CS – Miller Effect

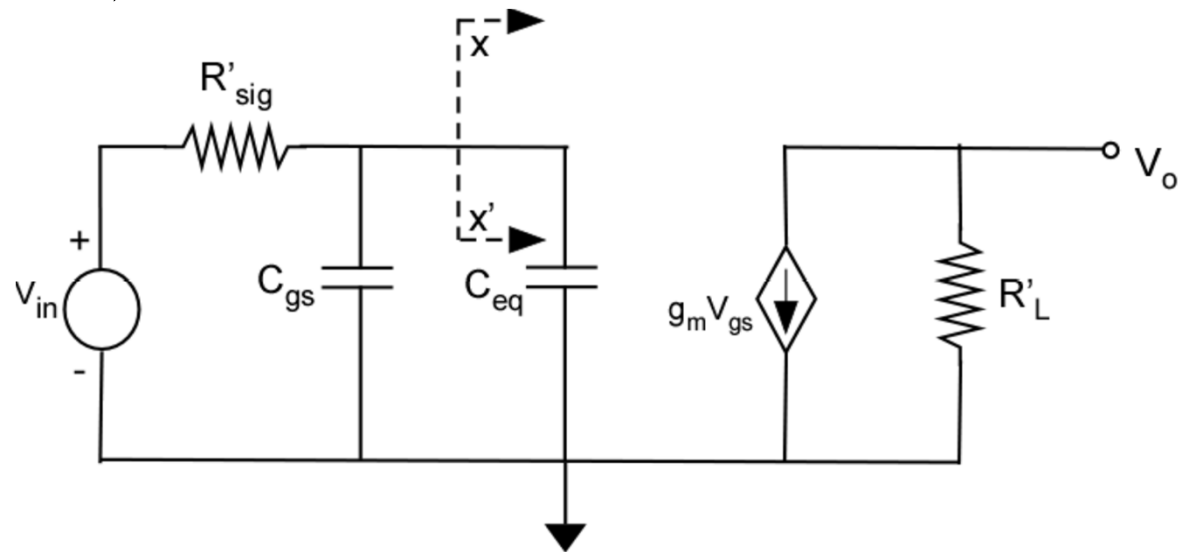
Define C_{eq} such that

$$sC_{eq}V_{gs} = sC_{gd} \left(1 + g_m R'_L\right) V_{gs}$$

$$V_o = -g_m R'_L V_{gs}$$

$$C_{eq} = C_{gd} \left(1 + g_m R'_L\right) = \text{Miller Capacitance}$$

$$v_{in} = \frac{R_g V_{sig}}{R_g + R_{sig}}$$



CS – Miller Effect

$$V_{gs} = \left(\frac{R_G V_{sig}}{R_G + R_{sig}} \right) \frac{1}{1 + jf / f_o}$$

f_o is the corner frequency of the STC circuit

$$f_o = \frac{1}{2\pi C_{in} R'_{sig}}$$

$$C_{in} = C_{gs} + C_{eq} = C_{gs} + \overbrace{C_{gd} (1 + g_m R'_L)}^{\text{Miller}}$$

CS – Miller Effect

$$\frac{V_o}{V_{sig}} = - \left(\frac{R_G}{R_G + R_{sig}} \right) g_m R'_L \frac{1}{1 + jf / f_o}$$

$$\frac{V_o}{V_{sig}} = \frac{A_M}{1 + jf / f_H}$$

$$f_H = f_o = \frac{1}{2\pi C_{in} R'_{sig}}$$

Example

$R_{sig} = 100 \text{ k}\Omega$, $R_G = 4.7 \text{ M}\Omega$, $R_D = 15 \text{ k}\Omega$, $g_m = 1 \text{ mA/V}$,
 $r_{ds} = 150 \text{ k}\Omega$, $R_L = 10 \text{ k}\Omega$, $C_{gs} = 1 \text{ pF}$ and $C_{gd} = 0.4 \text{ pF}$

$$R'_L = r_{ds} \parallel R_D \parallel R_L = 150 \parallel 15 \parallel 15 = 7.14 \text{ k}\Omega$$

$$A_M = -\frac{R_G}{R_G + R_{sig}} g_m R'_L = -\frac{4.7}{4.7 + 0.1} \times 1 \times 7.14 = -7$$

$$\text{Miller Cap: } C_{eq} = C_M = (1 + g_m R'_L) C_{gd}$$

$$C_M = 0.4 \times (1 + 7.14) = 3.26 \text{ pF}$$

Example (cont')

$$C_{in} = 1.0 + 3.26 = 4.26 \text{ pF}$$

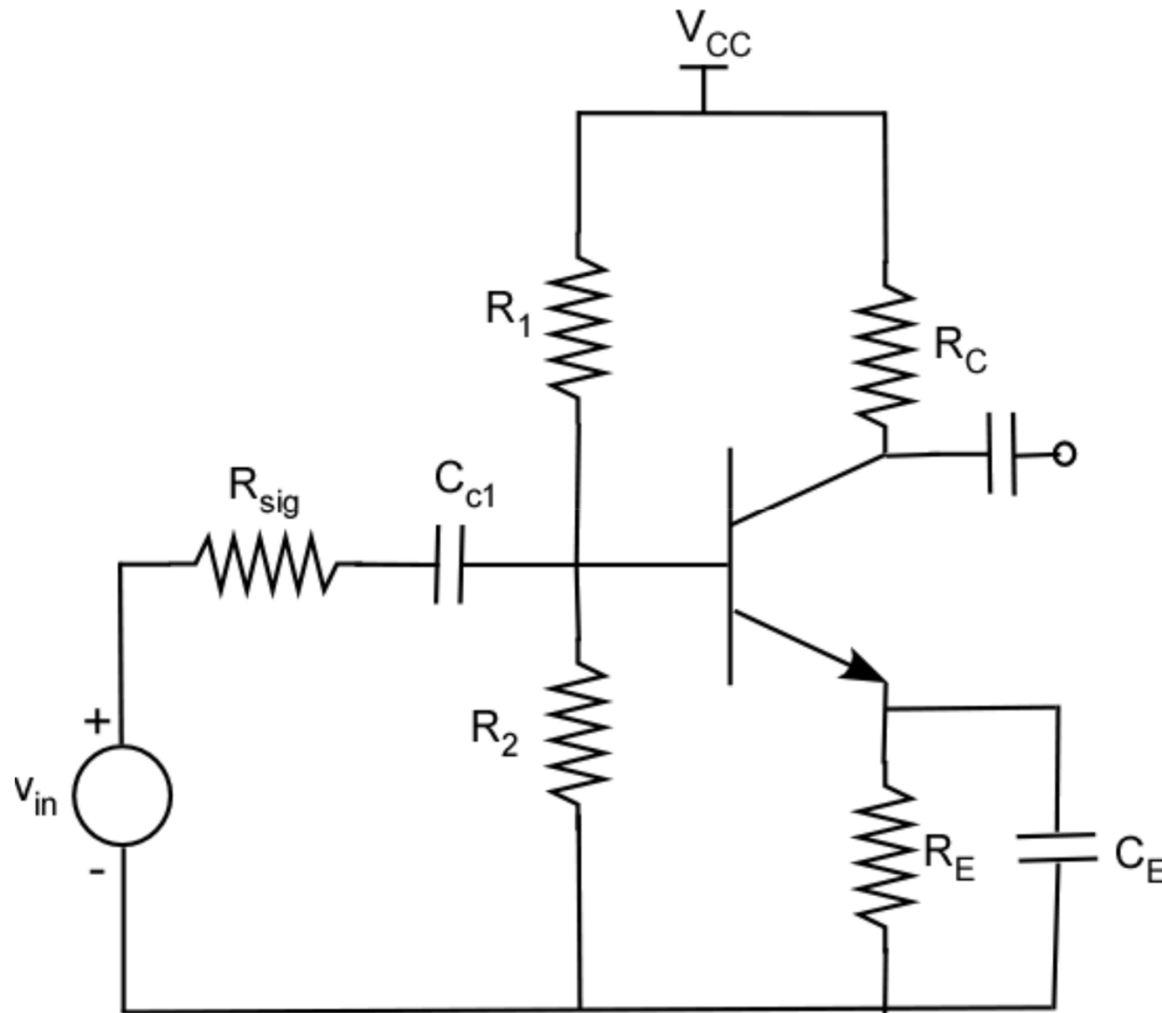
Upper 3 dB frequency is at:

$$f_H = \frac{1}{2\pi C_{in} (R_{sig} \parallel R_G)}$$

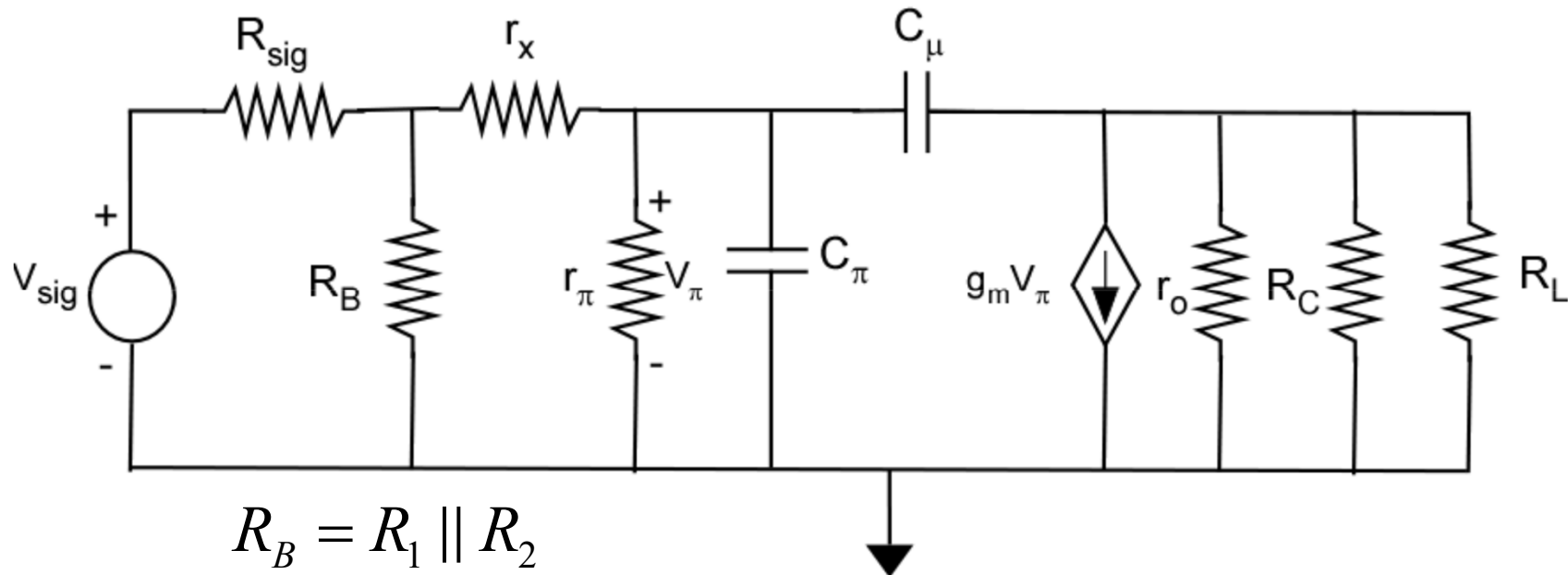
$$f_H = \frac{1}{2\pi \times 4.26 \times 10^{-12} \times (0.1 \parallel 4.7) \times 10^6} = 3.82 \text{ kHz}$$

$$f_H = 3.82 \text{ kHz}$$

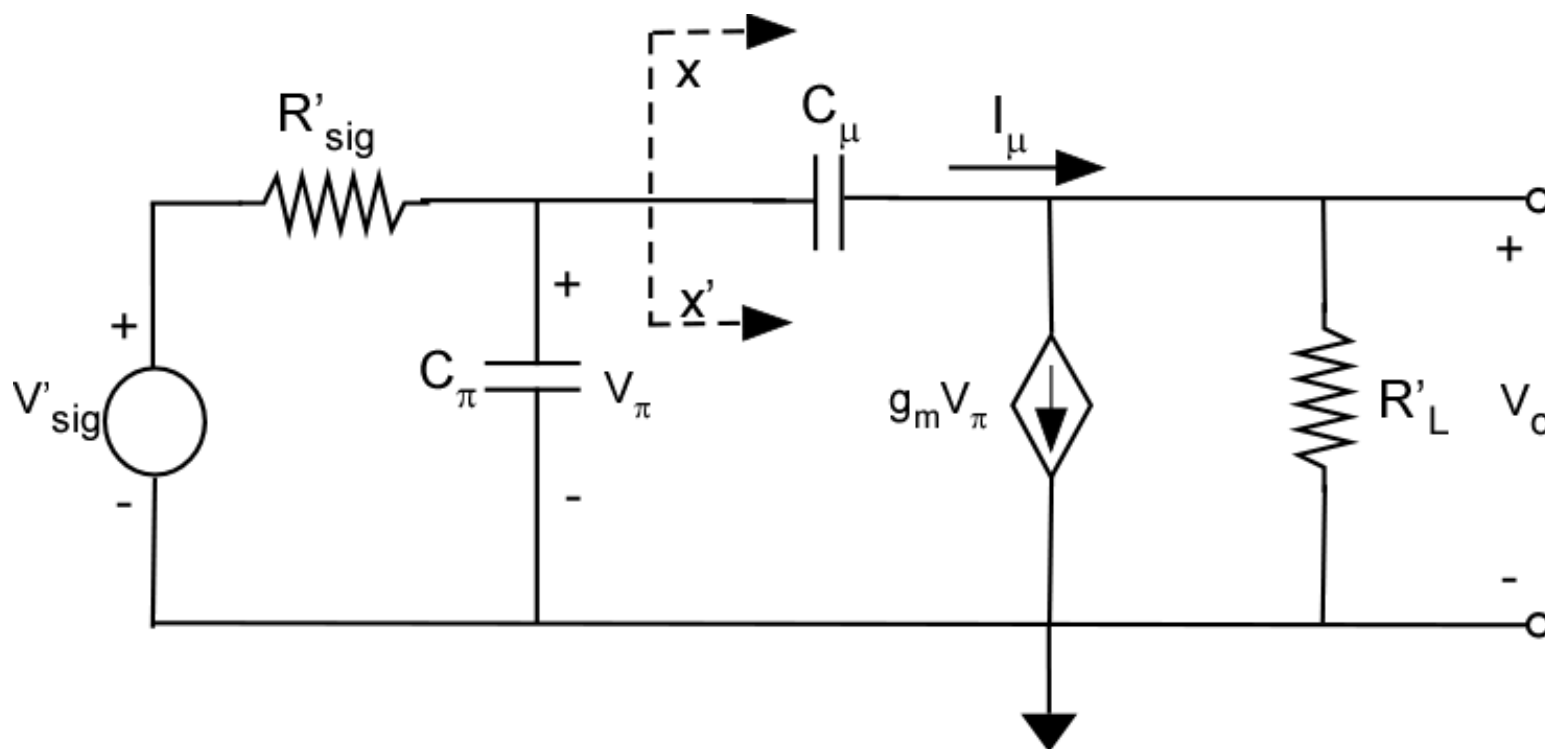
CE High-Frequency Model



CE High-Frequency Model



CE High-Frequency Model



$$V'_{sig} = V_{sig} \cdot \frac{R_B}{R_B + R_{sig}} \cdot \frac{r_\pi}{r_\pi + r_x + (R_{sig} \parallel R_B)}$$

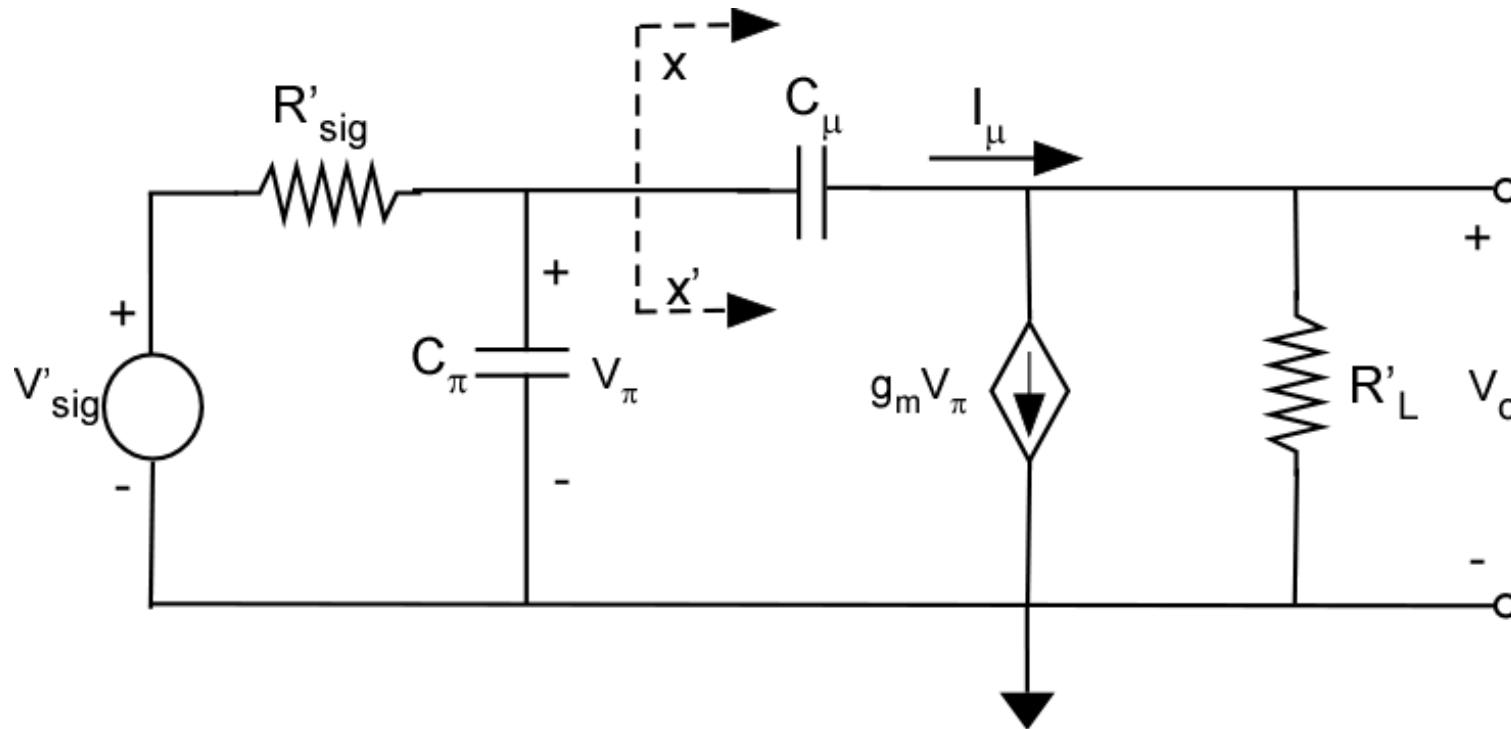
CE High-Frequency Model

$$R'_{sig} = r_{\pi} \parallel \left[r_x + \left(R_{sig} \parallel R_B \right) \right]$$

$$R'_L = r_o \parallel R_C \parallel R_L$$

$$V_o \simeq -g_m v_{\pi} R'_L$$

Bipolar Miller Effect



The left hand side of the circuit at XX' knows the existence of C_μ only through the current $I_\mu \rightarrow$ replace C_μ with C_{eq} from base to ground

Bipolar Miller Effect

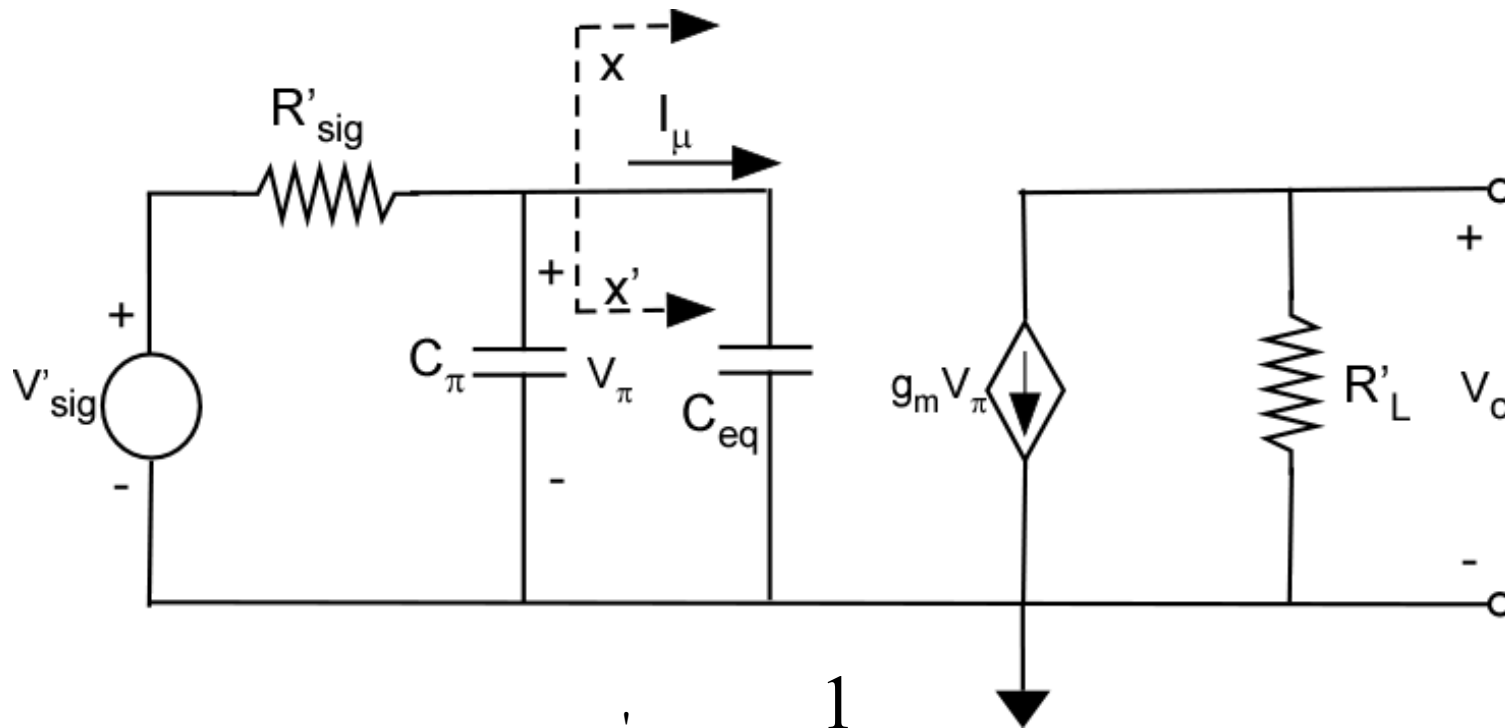
$$I_{\mu} = sC_{\mu} (v_{\pi} - v_o) = sC_{\mu} \left[v_{\pi} - (-g_m R'_L v_{\pi}) \right]$$

$$I_{\mu} = sC_{\mu} (1 + g_m R'_L) v_{\pi}$$

$$sC_{eq} v_{\pi} = I_{\mu} = sC_{\mu} (1 + g_m R'_L) v_{\pi}$$

$$C_{eq} = C_{\mu} (1 + g_m R'_L), \text{ Miller capacitance for BJT}$$

Bipolar Miller Effect



$$v_{\pi} = v'_{sig} \frac{1}{1 + jf / f_o}$$

$$f_o = \frac{1}{2\pi C_{in} R'_{sig}}$$

Bipolar Miller Effect (cont')

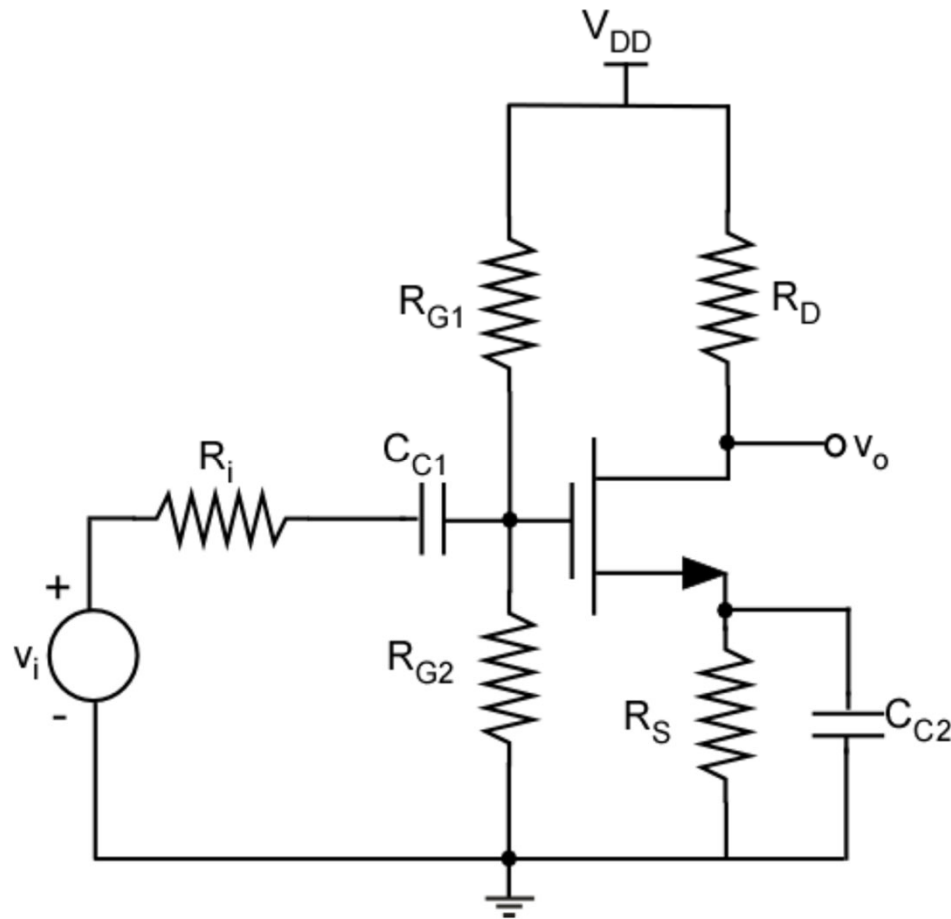
where $C_{in} = C_{\pi} + C_{eq} = C_{\pi} + C_{\mu} (1 + g_m R'_L)$

$$\frac{V_o}{V_{sig}} = \left[\frac{R_B}{R_B + R_{sig}} \cdot \frac{r_{\pi} g_m R'_L}{r_{\pi} + r_x + (R_{sig} \parallel R_B)} \right] \left[\frac{1}{1 + jf / f_o} \right]$$

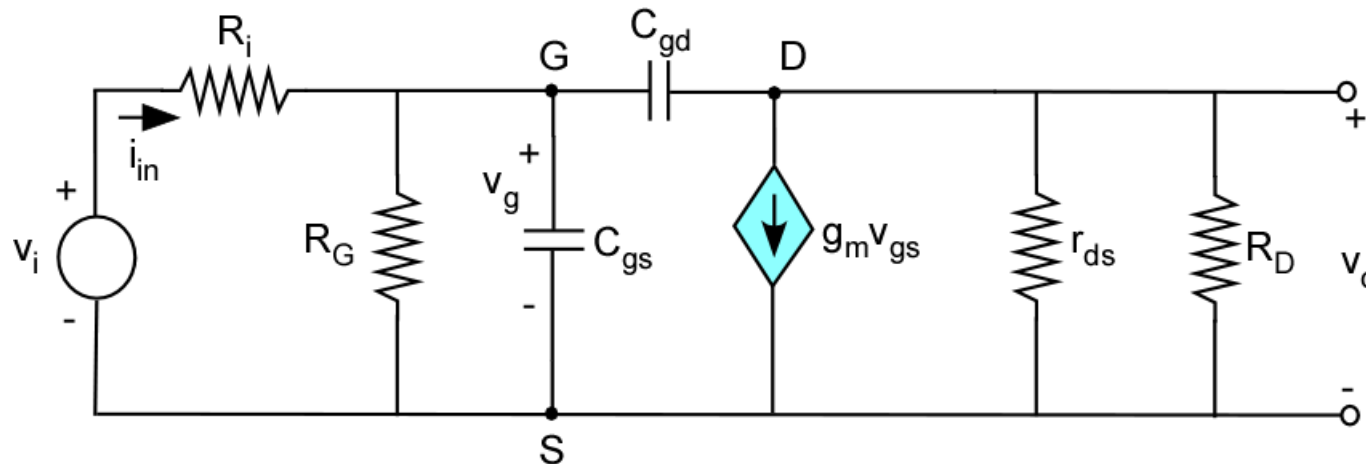
$$\frac{V_o}{V_{sig}} = A_M \frac{1}{1 + jf / f_o}$$

$$f_H = f_o = \frac{1}{2\pi C_{in} R'_{sig}}$$

CS – Miller Effect – Exact Analysis



CS – Miller Effect – Exact Analysis



$$G_i = \frac{1}{R_i} \quad G_D = \frac{1}{R_D} \quad G_g = \frac{1}{R_g} \quad g_{ds} = \frac{1}{r_{ds}} \quad R'_D = R_D \parallel r_{ds} = \frac{1}{G_D + g_{ds}}$$

$$\frac{v_o}{v_i} = - \frac{G_i R'_D (g_m - s C_{gd})}{G_i + G_g + s [C_{gs} + C_{gd}] + s C_{gd} R'_D [G_i + G_g] + s C_{gd} g_m R'_D + s^2 C_{gd} C_{gs} R'_D}$$

CS – Miller Effect – Exact Analysis

We neglect the terms in s^2 since

$$|s^2 C_{gd} C_{gs} R'_D| \ll |s C_{gd} g_m R'_D| \quad \text{or} \quad |s C_{gs}| \ll |g_m|$$

$$\frac{v_o}{v_i} = \frac{G_i R'_D (g_m - s C_{gd})}{G_i + G_g + s \left[C_{gs} + \underbrace{C_{gd} (1 + g_m R'_D)}_{\text{Miller}} + C_{gd} R'_D (G_i + G_g) \right]}$$

If we multiply through by $R_i = \frac{1}{G_i}$

CS – Miller Effect – Exact Analysis

$$\frac{v_o}{v_i} = - \frac{R'_D (g_m - sC_{gd})}{1 + R_i G_g + s \left\{ R_i \left[C_{gs} + C_{gd} (1 + g_m R'_D) \right] + C_{gd} R'_D (1 + R_s G_g) \right\}}$$

From which we extract the 3-dB frequency point

$$f_H = \frac{1 + R_i G_g}{2\pi \left\{ R_i \left[C_{gs} + C_{gd} (1 + g_m R'_D) \right] + C_{gd} R'_D (1 + R_i G_g) \right\}}$$

CS – Miller Effect – Exact Analysis

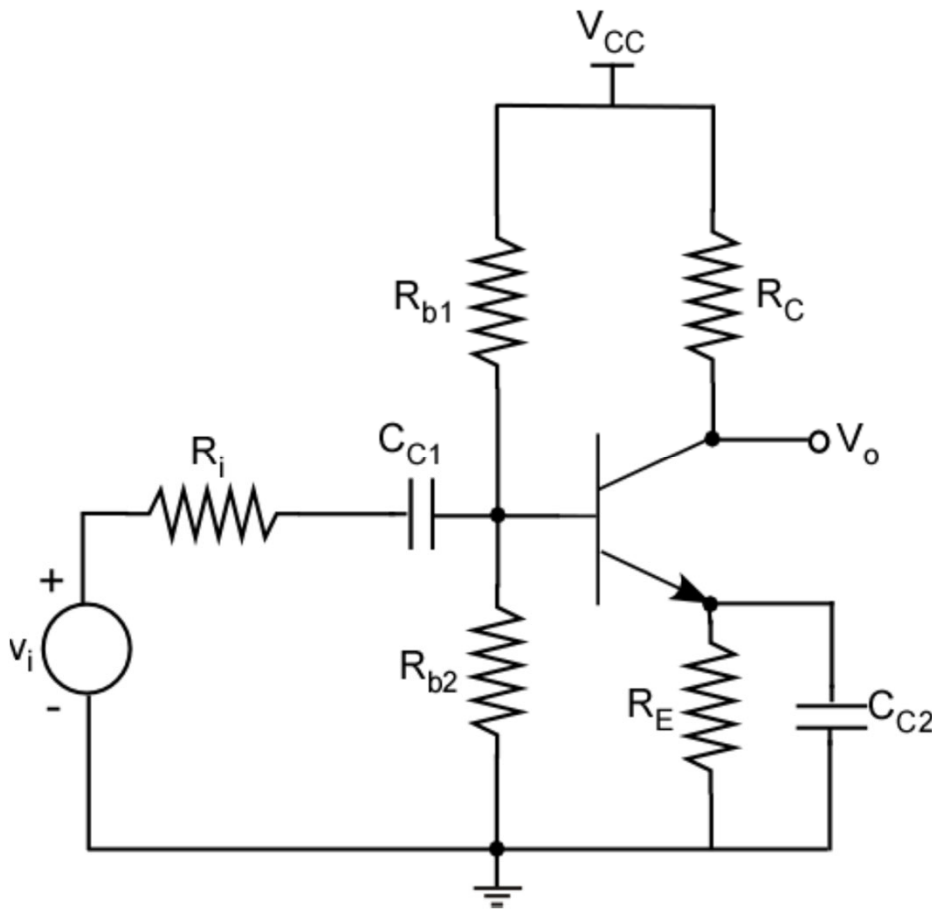
If G_g is negligible

$$f_H \approx \frac{1}{2\pi \left\{ R_i \left[C_{gs} + C_{gd} (1 + g_m R'_D) \right] + C_{gd} R'_D \right\}}$$

If $R_i = 0$

$$f_H \approx \frac{1}{2\pi C_{gd} R'_D}$$

BJT-CE – Miller Effect – Exact Analysis



$$G_i = \frac{1}{R_i}$$

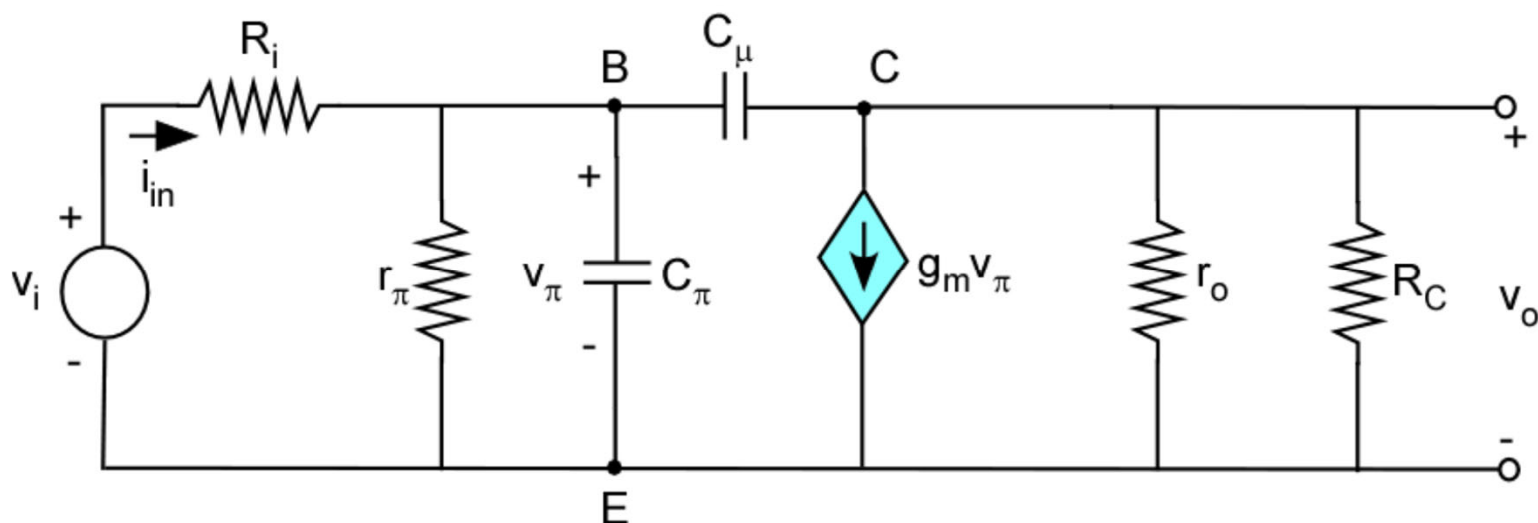
$$G_C = \frac{1}{R_C}$$

$$g_\pi = \frac{1}{r_\pi}$$

$$g_o = \frac{1}{r_o}$$

$$R'_C = R_C \parallel r_o = \frac{1}{G_C + g_o}$$

BJT-CE – Miller Effect – Exact Analysis



$$\frac{v_o}{v_i} = \frac{G_s R'_C (g_m - s C_\mu)}{G_i + g_\pi + s [C_\pi + C_\mu] + s C_\mu R'_C [G_i + g_\pi] + s C_\mu g_m R'_C + s^2 C_\mu C_\pi R'_C}$$

BJT-CE – Miller Effect – Exact Analysis

We neglect the terms in s^2 since

$$|s^2 C_\mu C_\pi R'_C| \ll |s C_\mu g_m R'_C| \quad \text{or} \quad |s C_\pi| \ll |g_m|$$

$$\frac{v_o}{v_i} = - \frac{G_i R'_C (g_m - s C_\mu)}{G_i + g_\pi + s \left[C_\pi + \underbrace{C_\mu (1 + g_m R'_C)}_{\text{Miller}} + C_\mu R'_C (G_i + g_\pi) \right]}$$

If we multiply through by $R_i = \frac{1}{G_i}$

$$\frac{v_o}{v_i} = - \frac{R'_C (g_m - s C_\mu)}{1 + R_i g_\pi + s \left\{ R_i \left[C_\pi + C_\mu (1 + g_m R'_C) \right] + C_\mu R'_C (1 + R_i g_\pi) \right\}}$$

BJT-CE – Miller Effect – Exact Analysis

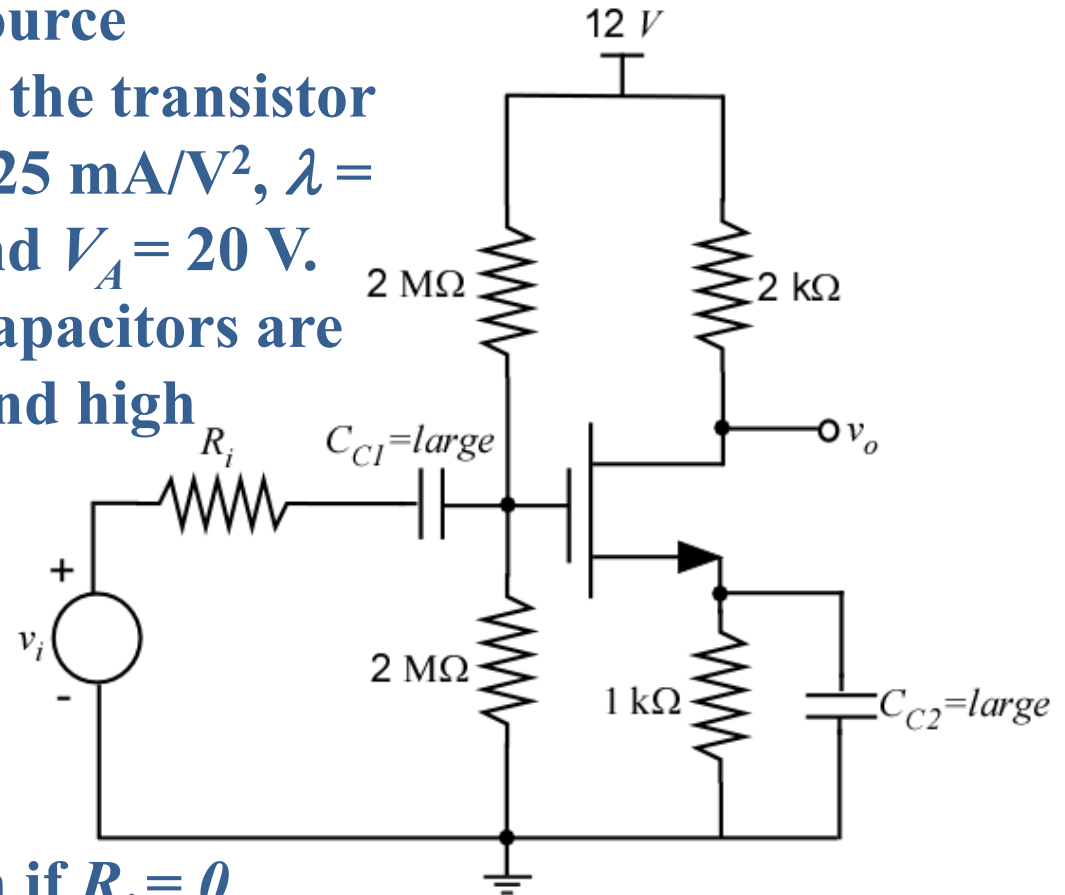
$$f_H = \frac{1 + R_i g_\pi}{2\pi \left\{ R_i \left[C_\pi + C_\mu (1 + g_m R'_C) \right] + C_\mu R'_C (1 + R_i g_\pi) \right\}}$$

If $R_i = 0$

$$f_H \approx \frac{1}{2\pi C_\mu R'_C}$$

Example

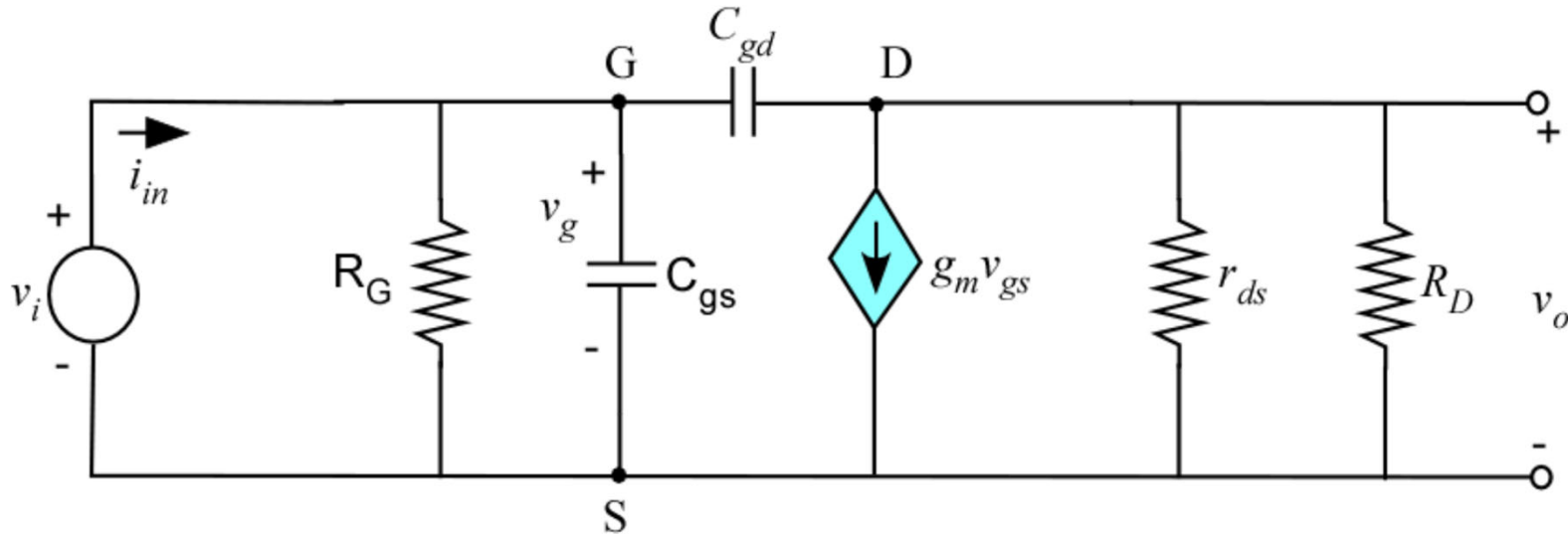
For the discrete common-source MOSFET amplifier shown, the transistor has $V_T = 1\text{V}$, $\mu C_{ox}(W/L) = 0.25\text{ mA/V}^2$, $\lambda = 0$, $C_{gs} = 3\text{ pF}$, $C_{gd} = 2.7\text{ pF}$ and $V_A = 20\text{ V}$. Assume that the coupling capacitors are short circuits at midband and high frequencies.



(a) Find the 3dB bandwidth if $R_i = 0$

(b) Find the 3dB bandwidth if $R_i = 50\text{ k}\Omega$

Example – Part (a)

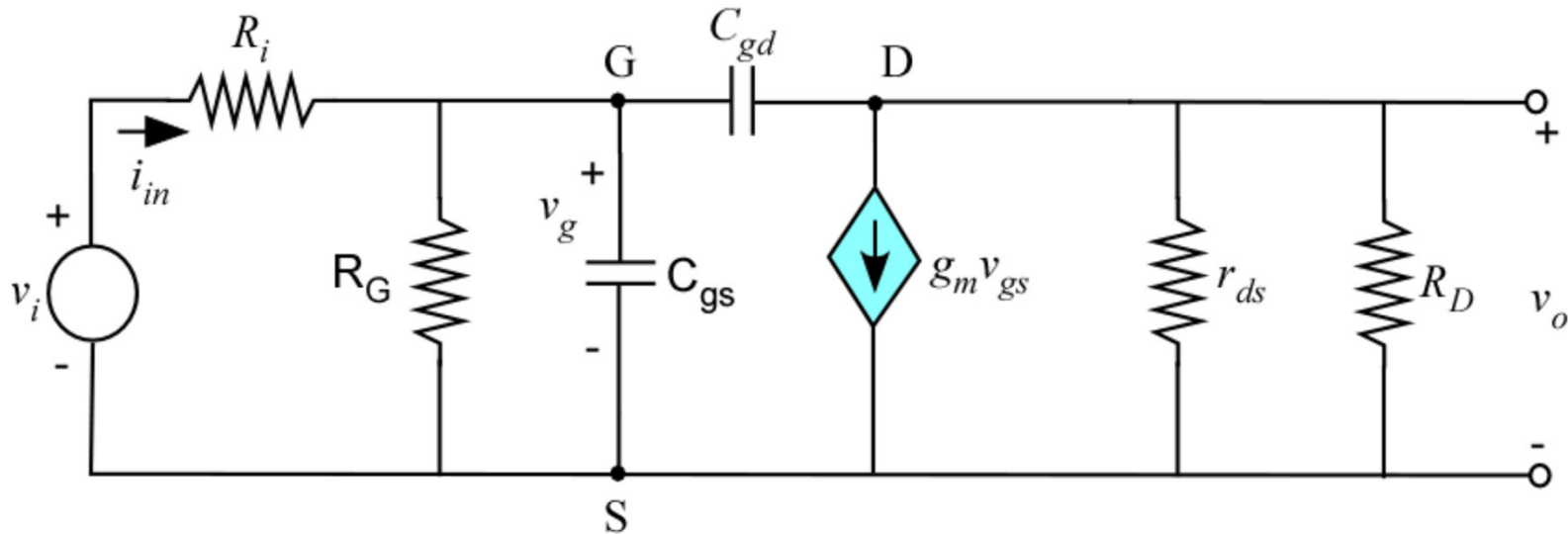


$$\text{If } R_i = 0, \quad f_{3dB} = \frac{1}{2\pi C_{gd} R'_D} \quad r_{ds} = \frac{|V_A|}{I_D} = \frac{20}{1.516} = 13 \text{ k}\Omega$$

$$R'_D = R_D \parallel r_{ds} = 13 \parallel 2 = 1.736 \text{ k}\Omega$$

$$f_{3dB} = \frac{1}{2\pi 2.7 \times 10^{-12} \times 1.736 \times 10^3} = 33.95 \text{ MHz}$$

Example Part (b)



If $R_i = 50 \text{ k}\Omega$, $g_m R'_D = 0.870 \times 1.736 = 1.51$

$$f_H \approx \frac{1}{2\pi \left\{ R_i \left[C_{gs} + C_{gd} (1 + g_m R'_D) \right] + C_{gd} R'_D \right\}}$$

$$f_H \approx \frac{1}{2\pi \left\{ 50 \left[3 + 2.7 (1 + 1.51) \right] + 2.7 \times 1.736 \right\}} = 32.27 \text{ kHz}$$